2N5550, 2N5551

Preferred Device

Amplifier Transistors

NPN Silicon

Features

• These are Pb–Free Devices*

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Collector – Emitter Voltage	2N5550 2N5551	V _{CEO}	140 160	Vdc
Collector – Base Voltage	2N5550 2N5551	V _{CBO}	160 180	Vdc
Emitter – Base Voltage		V_{EBO}	6.0	Vdc
Collector Current – Continuous		Ι _C	600	mAdc
Total Device Dissipation @ $T_A = 25^{\circ}C$ Derate above 25°C		P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C		PD	1.5 12	W m₩/°C
Operating and Storage Junction Temperature Range		T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

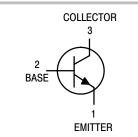
Characteristic	Symbol	Max	Unit	
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W	
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W	

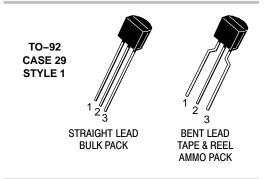
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



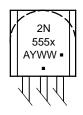
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MARKING DIAGRAM



x = 0 or 1 A = Assembly Location Y = Year WW = Work Week • = Pb-Free Package Wicrodot may be in either locat

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

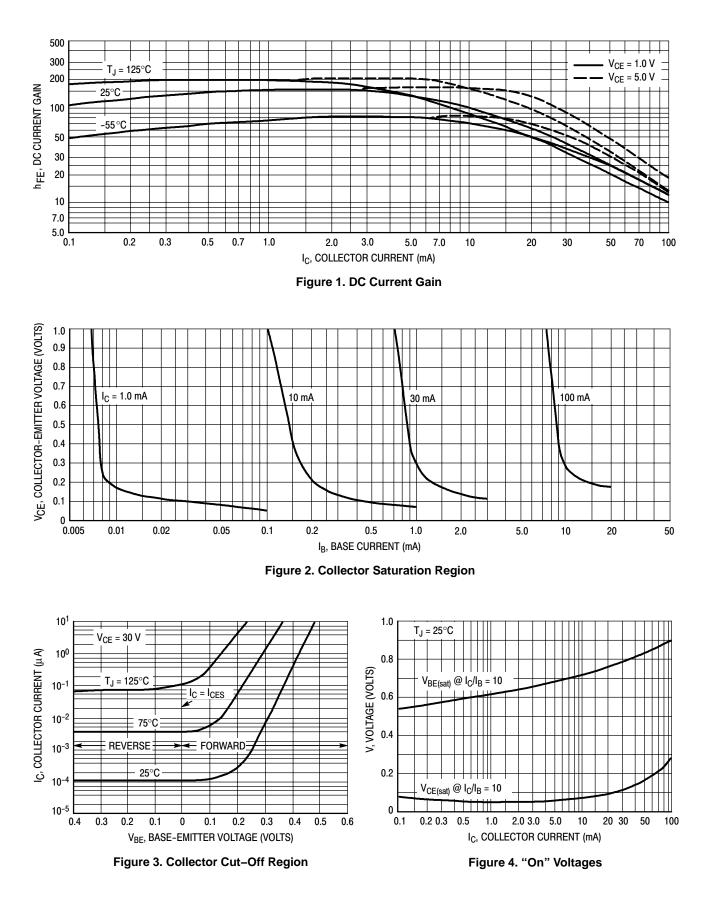
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

2N5550, 2N5551

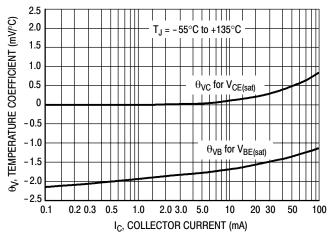
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS			•		•
Collector–Emitter Breakdown Voltage (Note 1) $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	2N5550 2N5551	V _{(BR)CEO}	140 160		Vdc
Collector–Base Breakdown Voltage ($I_C = 100 \ \mu Adc, I_E = 0$)	2N5550 2N5551	V _{(BR)CBO}	160 180		Vdc
Emitter–Base Breakdown Voltage ($I_E = 10 \ \mu Adc, I_C = 0$)		V _{(BR)EBO}	6.0	_	Vdc
	2N5550 2N5551 2N5550 2N5551	I _{CBO}	- - - -	100 50 100 50	nAdc μAdc
Emitter Cutoff Current ($V_{EB} = 4.0 \text{ Vdc}, I_{C} = 0$)		I _{EBO}	-	50	nAdc
ON CHARACTERISTICS (Note 1)	·		Į	4	ļ
DC Current Gain ($I_C = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$) ($I_C = 10 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$) ($I_C = 50 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$)	2N5550 2N5551 2N5550 2N5551 2N5551 2N5550	h _{FE}	60 80 60 80 20	- 250 250 -	_
Collector–Emitter Saturation Voltage ($I_C = 10$ mAdc, $I_B = 1.0$ mAdc) ($I_C = 50$ mAdc, $I_B = 5.0$ mAdc)	2N5551 Both Types 2N5550 2N5551	V _{CE(sat)}	30 - - -	- 0.15 0.25 0.20	Vdc
Base – Emitter Saturation Voltage $(I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc})$ $(I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc})$	Both Types 2N5550 2N5551	V _{BE(sat)}	- - -	1.0 1.2 1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current–Gain — Bandwidth Product ($I_C = 10 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 100 \text{ MHz}$)		f _T	100	300	MHz
Output Capacitance (V_{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz)		C _{obo}	-	6.0	pF
Input Capacitance (V_{EB} = 0.5 Vdc, I _C = 0, f = 1.0 MHz)	2N5550 2N5551	C _{ibo}		30 20	pF
Small–Signal Current Gain ($I_C = 1.0 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$, f = 1.0 kHz)		h _{fe}	50	200	-
Noise Figure (I _C = 250 μ Adc, V _{CE} = 5.0 Vdc, R _S = 1.0 kΩ, f = 1.0 kHz)	2N5550 2N5551	NF		10 8.0	dB

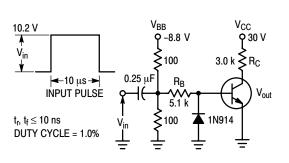
1. Pulse Test: Pulse Width $\leq 300~\mu s,$ Duty Cycle $\leq 2.0\%.$



2N5550, 2N5551

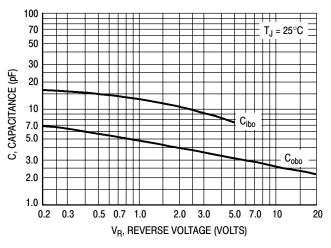




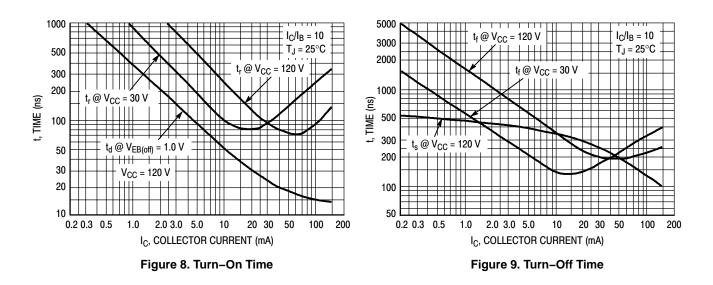


Values Shown are for $I_C @ 10 \mbox{ mA}$

Figure 6. Switching Time Test Circuit







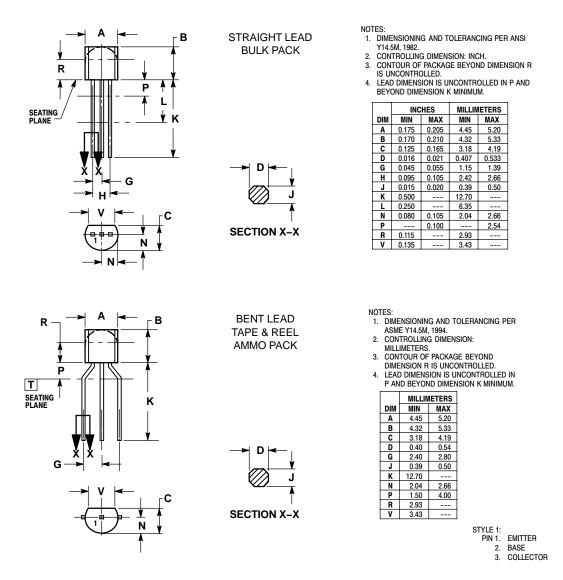
ORDERING INFORMATION

Device	Package	Shipping [†]	
2N5550G	TO-92 (Pb-Free)	5000 Units / Bulk	
2N5550RLRPG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box	
2N5551G	TO-92 (Pb-Free)	5000 Units / Bulk	
2N5551RL1G	TO-92 (Pb-Free)	2020 / Tana & Daal	
2N5551RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel	
2N5551RLRPG	TO-92 (Pb-Free)	- 2000 / Tape & Ammo Box	
2N55551ZL1G	TO-92 (Pb-Free)		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AM



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